V_{DSS}	650	V
I_D	15	A
$R_{DS(ON)}$	0.25	Ω

Features

Ultra low $R_{DS(on)}$
Ultra low gate charge (typ. Q_g=28.2nC)
100% UIS tested
RoHS compliant

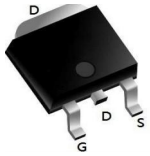
GK XXX
C65R250

Applications

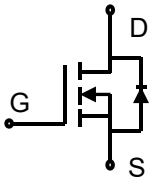
Power factor correction (PFC).
Switched mode power supplies (SMPS).
Uninterruptible power supply (UPS).

LOGO GK XXX CODE
C65 R 250
VDSS $R_{DS(on)}$

TO-252



Equivalent Circuit



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings (@ T = 25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	650	V
Continuous drain current [1] (T_C = 25°C)	I_D	15	A
(T_C = 100°C)		9.5	A
Pulsed drain current [2]	I_{DM}	45	A
Gate-Source voltage	V_{GSS}	±30	V
Avalanche energy, single pulse [3]	E_{AS}	281.6	mJ
Power Dissipation	P_D	158	W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C
Continuous diode forward current	I_S	15	A
Diode pulse current	$I_{S,pulse}$	45	A

Electrical Characteristics (T_J=25℃unless otherwise noted)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static characteristics						
Drain-source breakdown voltage	BV_{DSS}	V_{GS}=0V, I_D=250uA	650	-	-	V
Gate threshold voltage	$V_{GS(th)}$	V_{DS}=V_{GS}, I_D=250uA	2.5	3.5	4.5	V
Drain cut-off current	I_{DSS}	V_{DS}=650V, V_{GS}=0 V,T_j =25°C	-	-	1	μA
Gate leakage current, Forward	I_{GSSF}	V_{GS}=30V, V_{DS}=0 V	-	-	100	nA
Gate leakage current, Reverse	I_{GSSR}	V_{GS}=-30V, V_{DS}=0 V	-	-	-100	nA
Drain-source on-state resistance	$R_{DS(on)}$	V_{GS}=10V, I_D=7.5A T_j = 25°C T_j = 150°C	- - -	 0.25 0.62	 0.28 -	Ω
Gate resistance	R_G	f=1 MHz, open drain	-	5.71	-	Ω
Dynamic characteristics						
Input capacitance	C_{iss}	V_{DS} =100V, V_{GS}=0V, f=250kHz	-	1203.9	-	pF
Output capacitance	C_{oss}		-	42.78	-	
Reverse transfer capacitance	C_{rss}		-	0.61	-	
Turn-on delay time	$t_{d(on)}$	V_{DD} =400V, I_D=7.5A R_G = 10Ω, V_{GS}=10V	-	58.7	-	ns
Rise time	t_r		-	13.3	-	
Turn-off delay time	$t_{d(off)}$		-	54.8	-	
Fall time	t_f		-	7.4	-	
Gate charge characteristics						
Gate to source charge	Q_{gs}	V_{DD}=520V, I_D=7.5A, V_{GS}=0 to 10 V	-	6.3	-	nC
Gate to drain charge	Q_{gd}		-	12.1	-	
Gate charge total	Q_g		-	28.2	-	
Gate plateau voltage	$V_{plateau}$		-	5.44	-	V
Reverse diode characteristics						
Diode forward voltage	V_{SD}	V_{GS}=0 V, I_F=7.5A	-	-	1.1	V
Reverse recovery time	t_{rr}	V_R=400V, I_F=7.5A, dI_F/dt=100 A/μs	-	262	-	ns
Reverse recovery charge	Q_{rr}		-	2552.2	-	nC
Peak reverse recovery current	I_{rrm}		-	21.02	-	A

Notes:

1. Limited by maximum junction temperature and duty cycle.
2. Limited by maximum junction temperature, maximum duty cycle is 0.75.
3. I_{AS}=3.2A, L=55mH, V_{DD}=60V, Starting Tj= 25°C.
4. The value of R_{thJA} is measured by placing the device in a still air box which is one cubic foot.

Thermal Characteristics

Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	0.79	°C/W
Thermal Resistance, Junction-to-Ambient, minimal Footprint [4)]	$R_{\theta JA}$	62	°C/W
Soldering temperature, wave soldering only allowed at leads. (1.6mm from case for 10s)	T_{sold}	260	°C

RATING AND CHARACTERISTIC CURVES

Figure 1. Typ. Output Characteristics

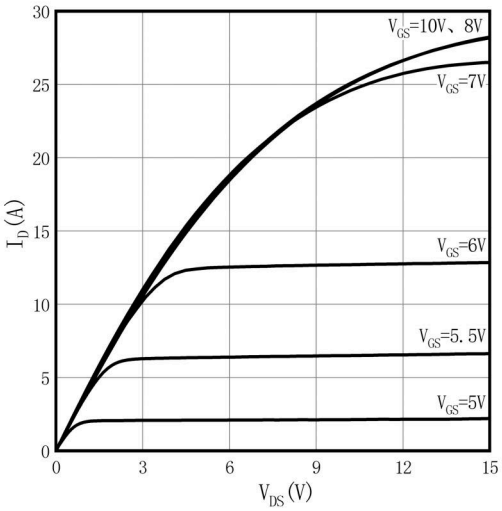


Figure 2. Transfer Characteristics

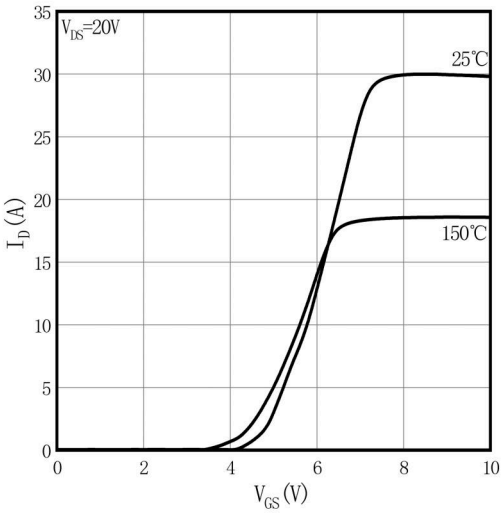


Figure 3. On-Resistance vs. Drain Current

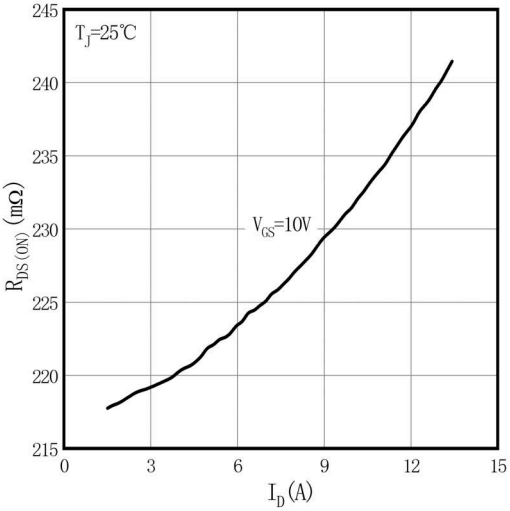


Figure 4.On-Resistance vs.Temperature

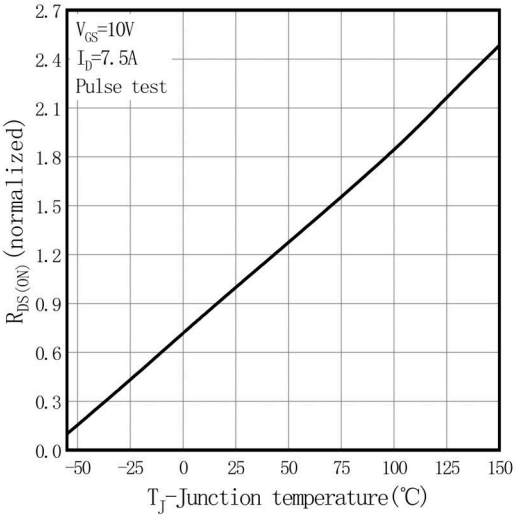


Figure 5.Breakdown Voltage vs.Temperature

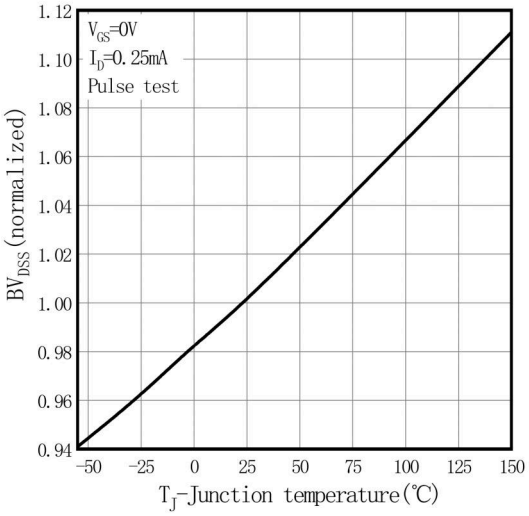
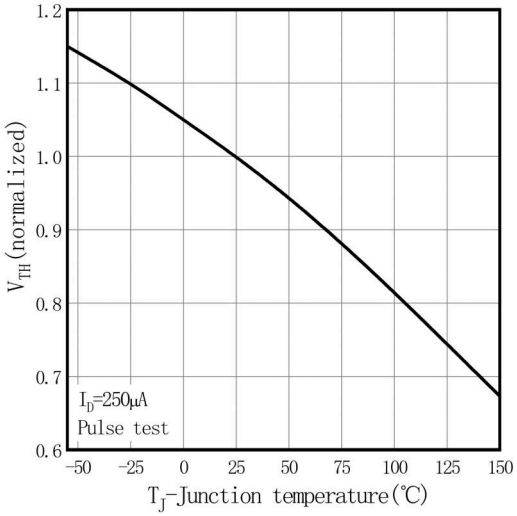


Figure 6.Threshold Voltage vs.Temperature



RATING AND CHARACTERISTIC CURVES

Figure 7.Body-Diode Characteristics

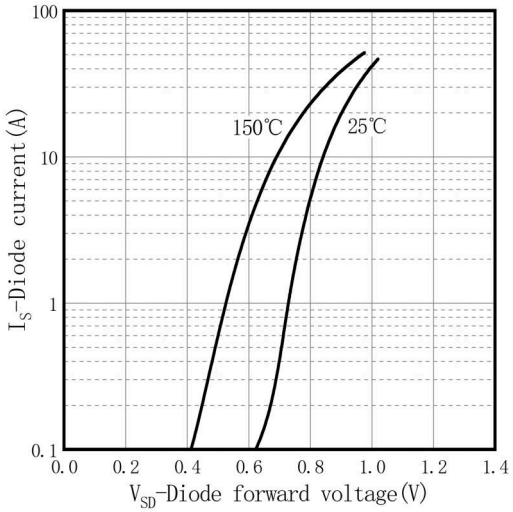


Figure 8.Capacitance Characteristics

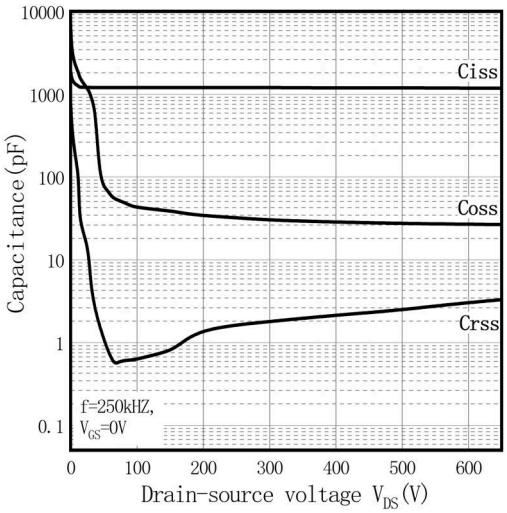


Figure 9.Gate Charge Characteristics

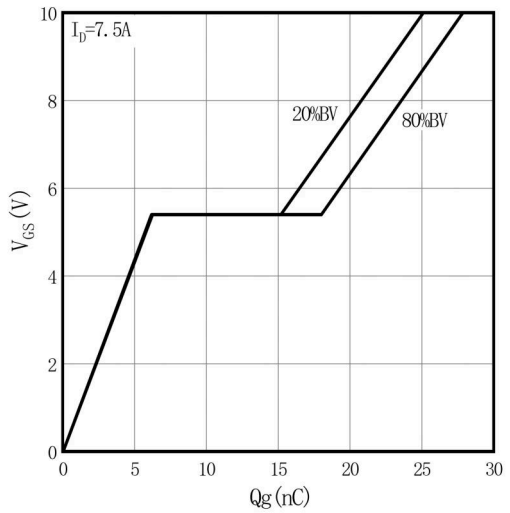


Figure 10.Drain Current Derating

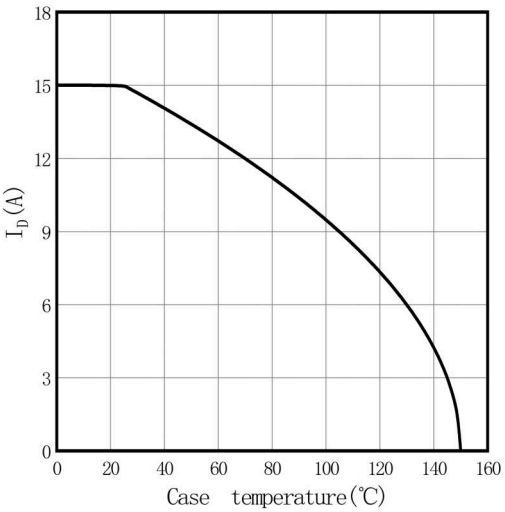
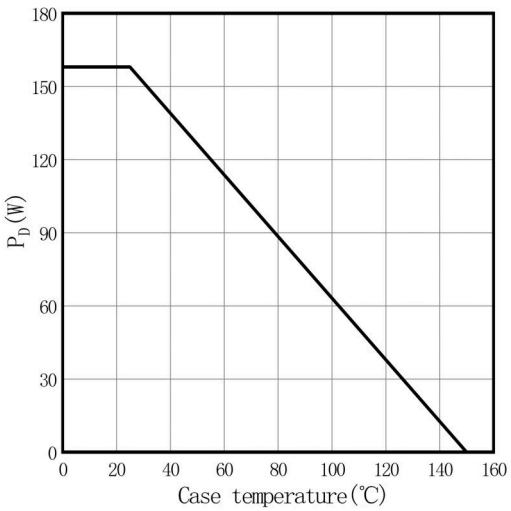
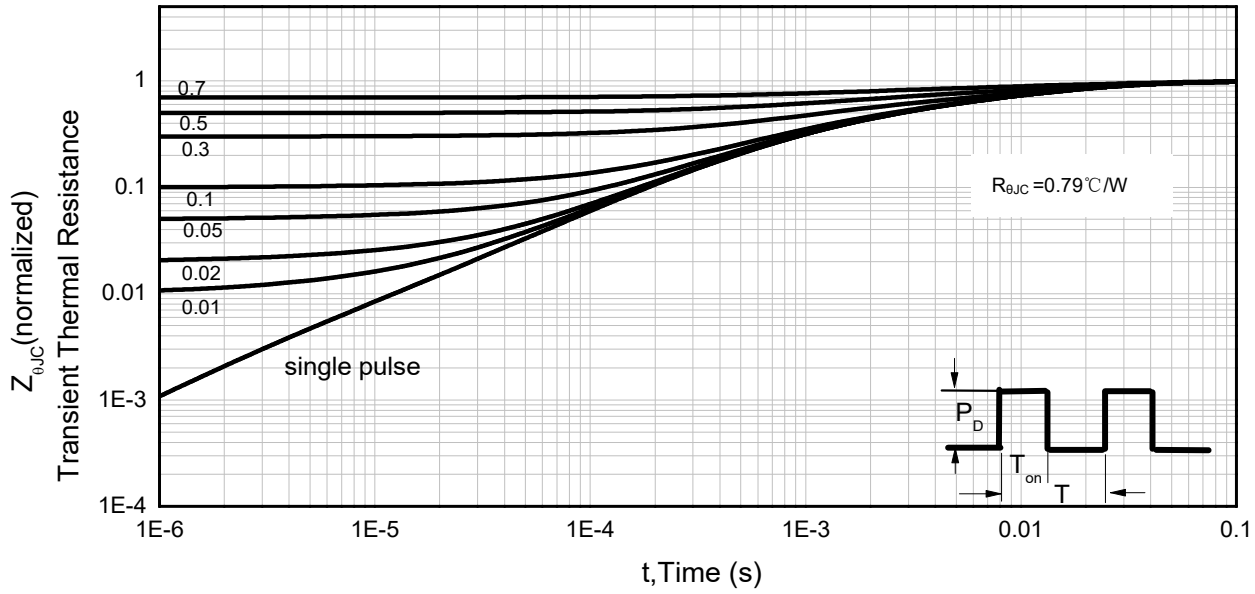


Figure 11.Power Dissipation vs.Temperature



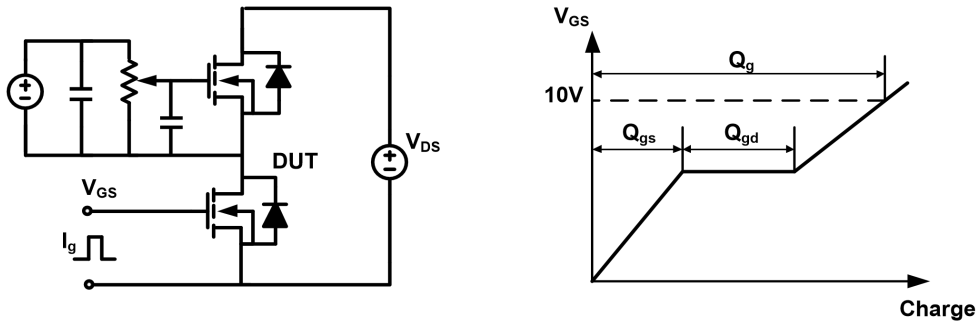
RATING AND CHARACTERISTIC CURVES

Figure 13. Normalized Maximum Transient Thermal Impedance (R_{thJC})

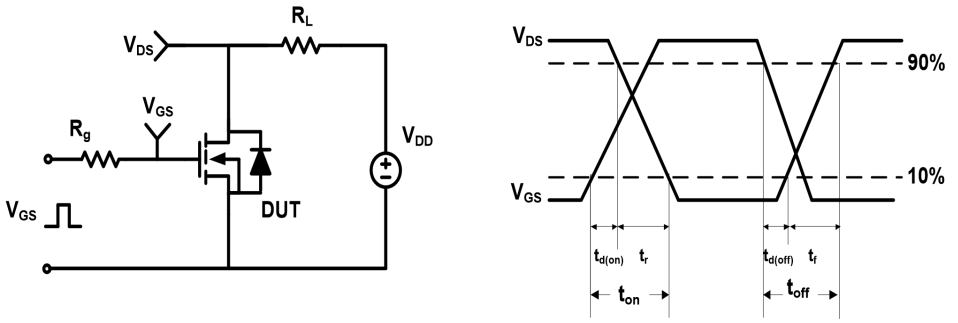


Test Circuit

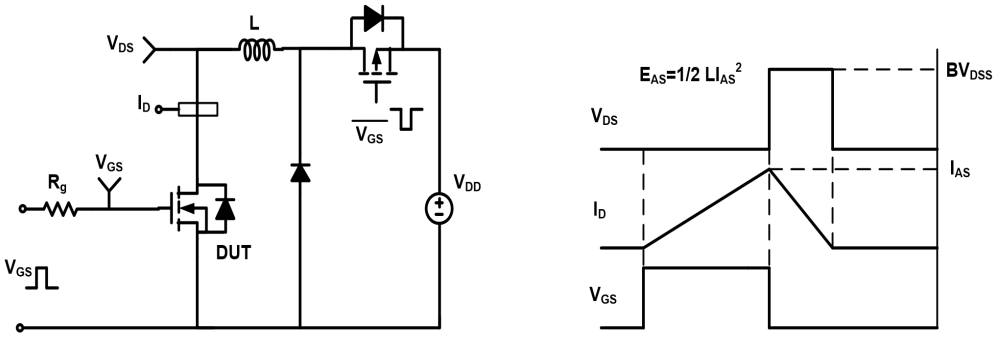
Gate Charge Test Circuit & Waveform



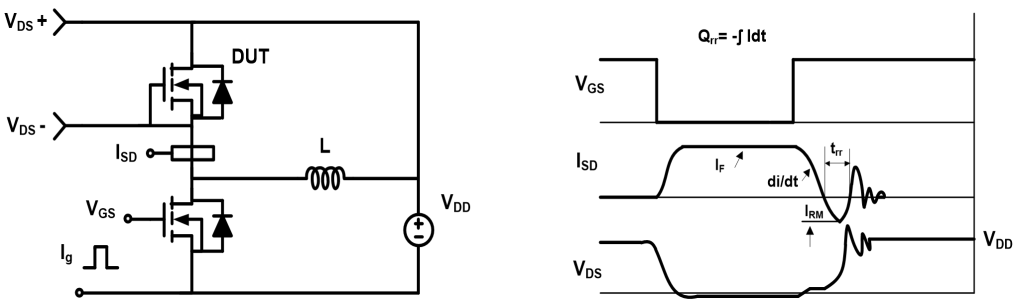
Resistive Switching Test Circuit & Waveform



Unclamped Inductive Switching (UIS) Test Circuit & Waveform



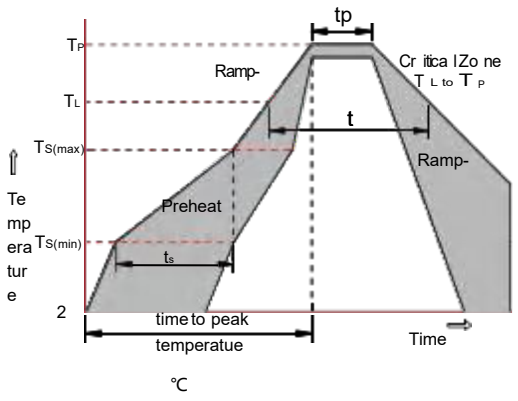
Diode Recovery Test Circuit & Waveform



Soldering parameters

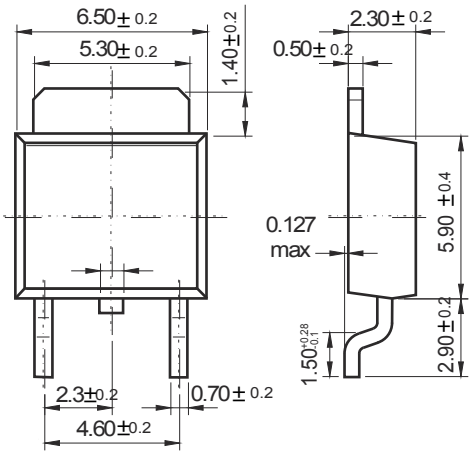
Reflow Condition		Pb-Free assembly (see as bellow)
Pre Heat	-Temperature Min ($T_{s(min)}$)	+150℃
	-Temperature Max($T_{s(max)}$)	+200℃
	-Time (Min to Max) (ts)	60-180 secs.
Average ramp up rate (Liquid us Temp (T_L) to peak)		3℃/sec. Max
$T_{s(max)}$ to T_L - Ramp-up Rate		3℃/sec. Max
Reflow	-Temperature(T_L)(Liquid us)	+217℃
	-Temperature(t_L)	60-150 secs.
Peak Temp (T_p)		+260(+0/-5)℃
Time within 5℃ of actual Peak Temp (t_p)		30 secs. Max
Ramp-down Rate		6℃/sec. Max
Time 25℃ to Peak Temp (T_P)		8 min. Max
Do not exceed		+260℃

FIG5: Reflow condition

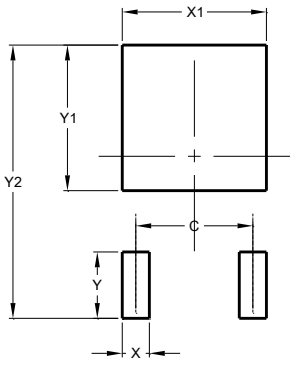


Package Dimensions & Suggested Pad Layout

TO-252



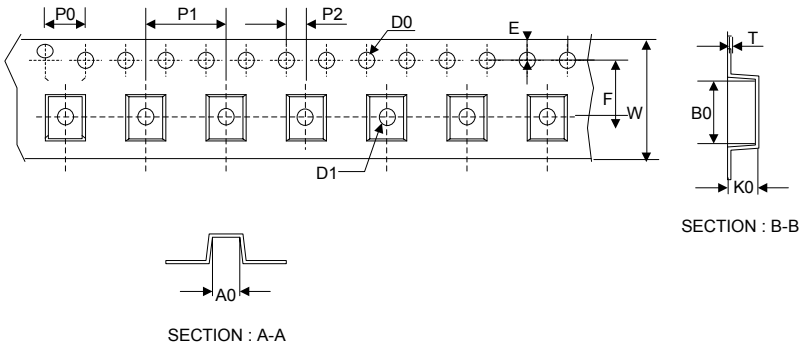
Dimensions in inches and (millimeters)



Dimensions	Value (in mm)
C	4.55
X	1.50
X1	5.80
Y	2.70
Y1	6.00
Y2	10.90

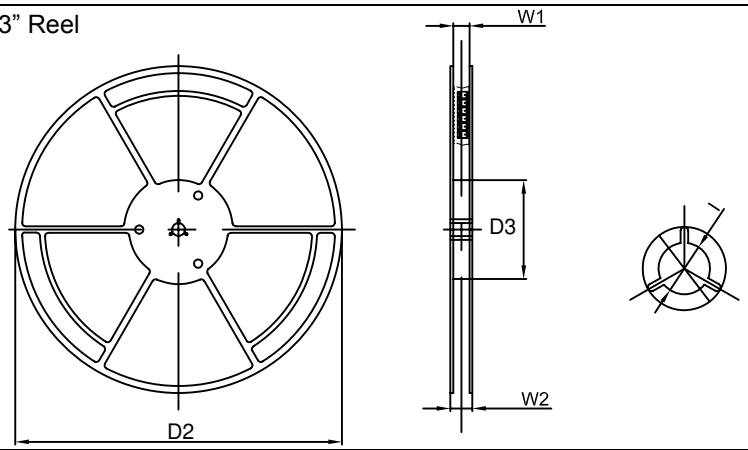
Tape & rell specification

Tape



Symbol	Dimension (mm)
P0	4.00±0.20
P1	8.00±0.20
P2	2.00±0.20
D0	1.55±0.15
D1	1.55±0.20
E	1.75±0.20
F	7.50±0.20
W	16.00±0.20
A0	7.10±0.20
B0	10.50±0.20
K0	2.70±0.20
T	0.30±0.10

13” Reel



D2	330.0±5.0
D3	100.0±4.0
W1	20.0±5.0
W2	25.0±5.0
I	13.0±2.0

Quantity: 2500PCS